

CGS702V

Commercial Low Skew PLL 1 to 9 CMOS Clock Driver with Improved EMI

General Description

The CGS702 is an off-the-shelf clock driver specifically designed for today's high speed processors. It provides low skew outputs which are produced at different frequencies from three fixed input references. The CGS702 is a reduced EMI version of the CGS700. The XTALIN input pin is designed to be driven from three distinct crystal oscillators running at 25 MHz, 33 MHz or 40 MHz.

The PLL, using a charge pump and an internal loop filter, multiplies this input frequency to create a maximum output frequency of four times the input.

The device includes a TRI-STATE® control pin to disable the outputs while the PLL is still in lock. This function allows testing the board without having to wait to acquire the lock once the testing is complete. (Continued)

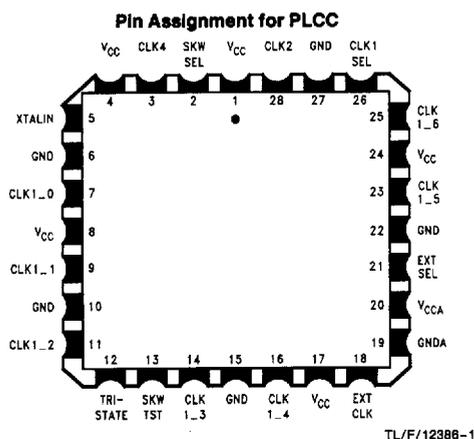
Features

- Reduced EMI compared to CGS700 (refer to EMI characteristics)

- Guaranteed and tested: 500 ps pin-to-pin skew (T_{OSHL} and T_{OSLH}) on 1x outputs
- Pentium™ and PowerPCTM compatible
- Output buffer of nine drivers for large fanout
- 25 MHz–160 MHz output frequency range
- Outputs operating at 4x, 2x, 1x of the reference frequency for multi-frequency bus applications
- Selectable output frequency
- Internal loop filter to reduce noise and jitter
- Separate Analog and digital V_{CC} and Ground pins
- Low frequency test mode by disabling the PLL
- Implemented on National's Core CMOS process
- Symmetric output current drive:
+30 mA/ -30 mA I_{OL}/I_{OH}
- 28-pin PCC for optimum skew performance
- Guaranteed 2 kV ESD protection

Ordering Code: See Section 5

Connection Diagram



Pin Description

PLCC Package

| Pin | Name | Description |
|-----|-----------|-----------------------------|
| 1 | V_{CC} | Digital V_{CC} |
| 2 | SKWSEL | Skew Test Selector Pin |
| 3 | CLK4 | 4x Clock Output |
| 4 | V_{CC} | Digital V_{CC} |
| 5 | XTALIN | Crystal Oscillator Input |
| 6 | GND | Digital Ground |
| 7 | CLK1_0 | 1x Clock Output |
| 8 | V_{CC} | Digital V_{CC} |
| 9 | CLK1_1 | 1x Clock Output |
| 10 | GND | Digital Ground |
| 11 | CLK1_2 | 1x Clock Output |
| 12 | TRI-STATE | Output TRI-STATE Control |
| 13 | SKWTST | Skew Testing Pin |
| 14 | CLK1_3 | 1x Clock Output |
| 15 | GND | Digital Ground |
| 16 | CLK1_4 | 1x Clock Output |
| 17 | V_{CC} | Digital V_{CC} |
| 18 | EXTCLK | External Test Clock |
| 19 | GND | Analog Ground |
| 20 | V_{CCA} | Analog V_{CC} |
| 21 | EXTSEL | External Clock MUX Selector |
| 22 | GND | Digital Ground |
| 23 | CLK1_5 | 1x Clock Output |
| 24 | V_{CC} | Digital V_{CC} |
| 25 | CLK1_6 | 1x Clock Output |
| 26 | CLK1SEL | CLK1 Multiplier Selector |
| 27 | GND | Digital Ground |
| 28 | CLK2 | 2x Clock Output |

General Description (Continued)

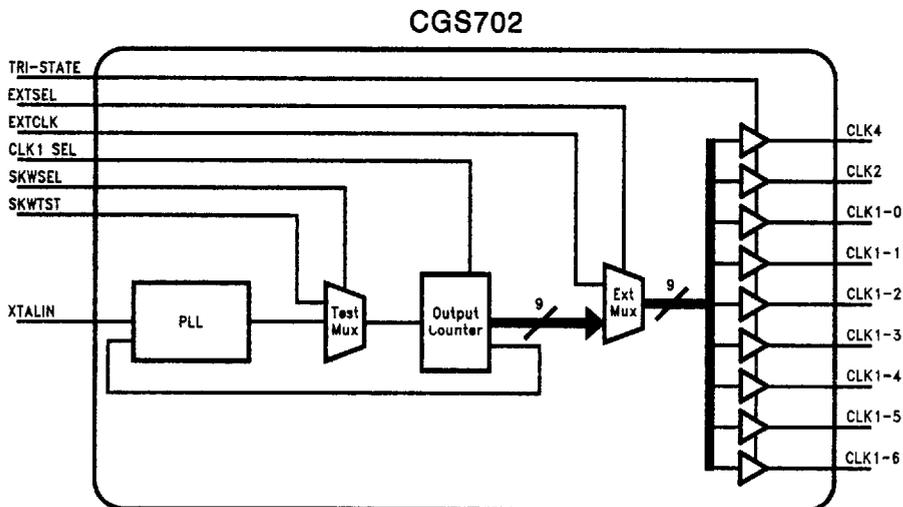
Also included, are two EXTSEL and EXTCLK pins to allow testing the chip via an external source. The EXTSEL pin, once set to high, causes the External-Clock_Mux to change its input from the output of the VCO and Counter to the external clock signal provided via EXTCLK input pin.

CLK1SEL pin changes the output frequency of the CLK1_0,6 outputs. During normal operation, when CLK1SEL pin is high, these outputs are at the same frequency as the input crystal oscillator, while CLK2 and CLK4 outputs are at twice and four times the input frequency respectively.

Once CLK1SEL pin is set to a low logic level, the CLK1 outputs will be at twice the input frequency, the same as the CLK2 output, with CLK4 output still being at four times the input frequency.

In addition two other pins are added for increasing the test capability. SKWSEL and SKWTST pins allow testing of the counter's output and skew of the output drivers by bypassing the VCO. In this test mode CLK4 frequency is the same as SKWTST input frequency, while CLK2 is $\frac{1}{2}$ and CLK1 frequencies are $\frac{1}{4}$ respectively (refer to the truth table). In addition CLK1SEL functionality is also true under this test condition.

Block Diagram



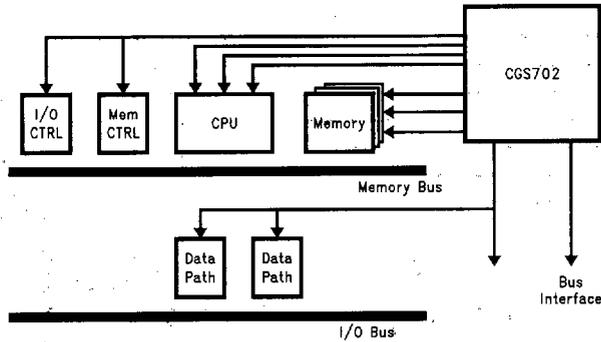
TL/F/12386-2

Truth Table

| Input | | | | | | Output | | |
|----------|---------|---------|---------|---------|-----------|---------------------|-----------------------|-----------------------|
| CLK1 SEL | EXT SEL | EXT CLK | SKW SEL | SKW TST | TRI-STATE | CLK4 | CLK2 | CLK1 |
| H* | L | X | L | X | H | 4x f _{IN} | 2x f _{IN} | f _{IN} |
| L* | L | X | L | X | H | 4x f _{IN} | 2x f _{IN} | 2x f _{IN} |
| X | H | | X | X | H | | | |
| H | L | X | H | | H | 1x f _{TST} | 1/2x f _{TST} | 1/4x f _{TST} |
| L | L | X | H | | H | 1x f _{TST} | 1/2x f _{TST} | 1/2x f _{TST} |
| X | X | X | X | X | L | Z | Z | Z |

*Steady state phase, frequency lock.

Typical Application



TL/F/12386-3

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

| | |
|--|--------------------------|
| Supply Voltage (V_{CC}) | -0.5V to 7.0V |
| DC Input Voltage Diode Current (I_{IK}) | |
| $V = -0.5V$ | -20 mA |
| $V = V_{CC} + 0.5V$ | +20 mA |
| DC Input Voltage (V_I) | -0.5V to $V_{CC} + 0.5V$ |
| DC Output Diode Current (I_O) | |
| $V = -0.5V$ | -20 mA |
| $V = V_{CC} + 0.5V$ | +20 mA |
| DC Output Voltage (V_O) | -0.5V to $V_{CC} + 0.5V$ |
| DC Output Source or Sink Current (I_O) | ± 60 mA |
| DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND}) | ± 60 mA |
| Storage Temperature (T_{STG}) | -65°C to +150°C |
| Junction Temperature | 150°C |
| Power Dissipation (Static and Dynamic) (Note 2) | 1400 mW |

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the DC and AC Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The Recommended Operating Conditions will define the conditions for actual device operation.

Note 2: Power dissipation is calculated using $49^\circ/W$ as the thermal coefficient for the PCC package at 225 LFM airflow. The input frequency is assumed at 33 MHz with CLK4 at 132 MHz and CLK2 and CLK1's being at 66 MHz. In addition the ambient temperature is assumed 70° with power supply at 5.0V.

Recommended Operating Conditions

| | |
|--|----------------|
| Supply Voltage (V_{CC}) | 4.5V to 5.5V |
| Input Voltage (V_I) | 0V to V_{CC} |
| Output Voltage (V_O) | 0V to V_{CC} |
| Input Crystal Frequency | 25 MHz-40 MHz |
| Operating Temperature (T_A) | 0°C to +70°C |
| External Clock Frequency (EXTCLK Pin) | 1 MHz-10 MHz |
| XTALIN Duty Cycle Range | 25/75 (75/25)% |
| Input Rise and Fall Times (0.8V to 2.0V) | |
| Crystal Input | 5 ns max. |
| All Other Inputs | 10 ns max. |

| Typical θ_{JA} | LFM | °C/W |
|-----------------------|-----|------|
| | 0 | 54 |
| | 225 | 45 |
| | 500 | 38 |
| | 900 | 34 |

DC Electrical Characteristics

over recommended operating free air temperature range. All typical values are measured at $V_{CC} = 5V, T_A = 25^\circ C$

| Symbol | Parameter | Conditions | V_{CC} | $V_{CC} = 4.5V$ to $5.5V$ $T = 0^\circ C$ to $70^\circ C$ | | | Units |
|-----------------------|--|---|----------|--|----------------|------|---------|
| | | | | Min | Typ | Max | |
| V_{IH} | Minimum Input High Level Voltage | | 4.5 | 2.0 | | | V |
| | | | 5.5 | 2.0 | | | |
| V_{IL} | Maximum Input Low Level Voltage | | 4.5 | | | 0.8 | V |
| | | | 5.5 | | | 0.8 | |
| V_{OH} | Minimum Output High Level Voltage | $I_{OH} = -50 \mu A$ | 4.5 | 4.4 | 4.4 | | V |
| | | $I_{OH} = -30 \mu A$ | 4.5 | $V_{CC} - 0.6$ | $V_{CC} - 0.6$ | | |
| V_{OL} | Maximum Output Low Level Voltage | $I_{OL} = 50 \mu A$ | 4.5 | | | 0.1 | V |
| | | $I_{OL} = 30 \mu A$ | 4.5 | | | 0.6 | |
| | | | 5.5 | | | 0.6 | |
| I_{OH} | High Level Output Current | $V_{OH} = V_{CC} - 1.0V$ | 4.5 | 50 | 110 | 170 | mA |
| I_{OL} | Low Level Output Current | $V_{OL} = 1.0V$ | 4.5 | 50 | 110 | 170 | mA |
| I_{IN} | Leakage Current | $V_{IN} = 0.4V$ or $4.6V$ | 4.5 | | | | μA |
| | | | 5.5 | -50 | | 50.0 | |
| $I_{OZL/H}$ | Output Leakage Current | $V_{IN} = GND$ $V_{OUT} = V_{CC}$ or GND | 5.5 | -5.0 | | +5.0 | μA |
| C_{IN} | Input Capacitance | | 4.5 | | | | pF |
| | | | 5.0 | | | 10.0 | |
| I_{CC} I_{CCT} | Quiescent Analog + Digital Current (No Load) | $V_{IN} = V_{CC}$ or GND | 5.5 | | 3 | 5.0 | mA |
| | I_{CC} per TTL Input | $V_{IN} = V_{CC} - 2.1$ or GND | 5.5 | | | 2.5 | |

CGS702 AC Electrical Characteristics

over recommended operating free air temperature range. All typical values are measured at $V_{CC} = 5V$, $T_A = 25^\circ C$

| Symbol | Parameter | | $V_{CC} = 4.5V$ to $5.5V$ $f_{IN} = 25$ MHz to 40 MHz $T = 0^\circ C$ to $70^\circ C$ $C_L =$ Circuit 1 and 2 $R_L =$ Circuit 1 and 2 | | | Units | Notes |
|-------------|---|--|---|----------------|---------------------|---------|-----------------|
| | | | Min | Typ | Max | | |
| t_{RISE} | Output Rise | CLK4 CLK2 CLK1 | 0.8V to 2.6V 1.0V to $V_{CC} - 1.0V$ 1.0V to $V_{CC} - 1.0V$ | | 2.0 | ns | (Note 1) |
| t_{FALL} | Output Fall | CLK4 CLK2 CLK1 | 2.6V to 0.8V $V_{CC} - 1.0V$ to 1.0V $V_{CC} - 1.0V$ to 1.0V | | 2.0 | ns | (Note 1) |
| t_{SKEW} | Maximum Edge-to-Edge Output Skew | + to + Edges + to + Edges + to + Edges | CLK1__CLK1 CLK1__CLK4 CLK2__CLK4 | | 500 1000 1500 | ps | (Note 2) |
| t_{LOCK} | Time to Lock the Output to the XTALIN Input | | | | 100 | μs | |
| t_{CYCLE} | Output Duty Cycle | CLK1 Outputs CLK2 Output CLK4 Output | | 49 49 35 | 51 51 65 | % | (Note 3) |
| J_{LT} | Output Jitter (Long Term) | | | | 300 | ps | (Notes 4, 5) |
| J_{CC} | Output Jitter (Cycle to Cycle) | CLK1 | | -75 | +75 | ps | (Notes 4, 5, 6) |
| | | CLK2 | | | ± 250 | ps | (Notes 4, 5, 7) |
| | | CLK4 | | | ± 250 | ps | (Notes 4, 5, 7) |
| F_{MIN} | Minimum XTALIN Frequency | | | | 15 | MHz | |
| F_{MAX} | Maximum XTALIN Frequency | | | | 43 | MHz | |

Note 1: t_{RISE} and t_{FALL} parameters are measured at the pin of the device

Note 2: Skew is measured at 50% of V_{CC} for CLK1 and CLK2. While it is measured at 1.4V for CLK4.

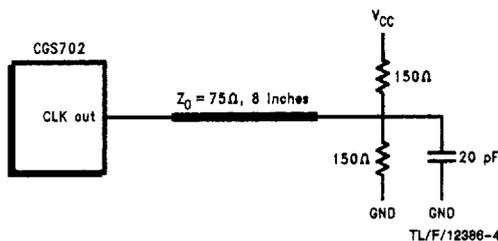
Note 3: Output duty cycle is measured at $V_{DD}/2$ for CLK1 and CLK2. While it is measured at 1.4V for CLK4.

Note 4: Jitter parameter is characterized and is guaranteed by design only. It measures the uncertainty of either the positive or the negative edge over 1000 cycles. It is also measured at output levels of $V_{CC}/2$. Refer to Figure 2 for further explanation.

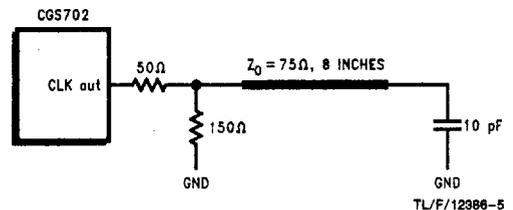
Note 5: The GNDA pins of the 702 must be as free of noise as possible for minimum jitter. Separate analog ground plane is recommended for the PCB. Also the V_{CCA} pin requires extra filtering to further reduce noise. Ferrite beads for filtering and bypass capacitors are suggested for V_{CCA} pin.

Note 6: Cycle to Cycle Jitter is measured at $V_{CC}/2$.

Note 7: Cycle to Cycle Jitter for CLK2 and CLK4 is only for $25^\circ C$, 5V measured @ $V_{CC}/2$.



Circuit 1. Test Circuit for CLK1 and CLK2



Circuit 2. Test Circuit for CLK4

CGS702 AC Electrical Characteristics (Continued)

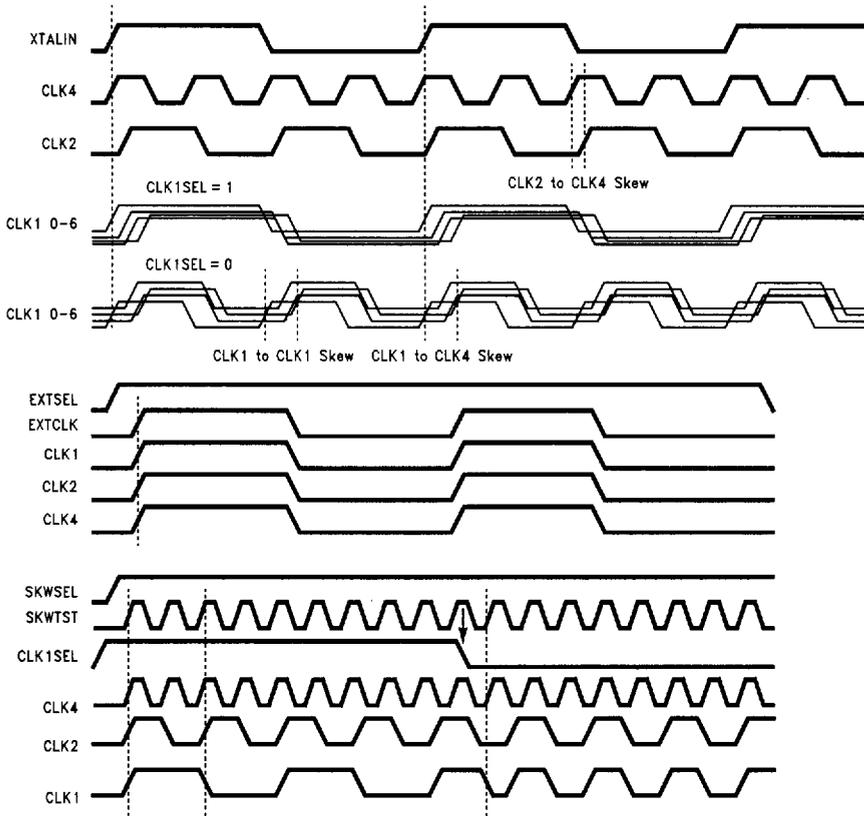
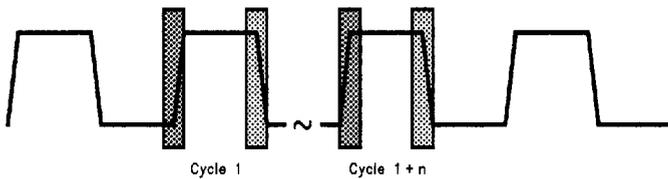


FIGURE 1. Waveforms

TL/F/12386-6



Jitter = |Period(1) - Period(n+1)| for either the rising or falling edge, where n is 1 to 1000 cycles.

FIGURE 2. Jitter

TL/F/12386-7

Application References and Bibliography

Information relating to EMI as well as general application hints are in the following application notes:
 AN-988 (EMI App Note)
 AN-640
 AN-991

EMI Characteristics and Measurements for CGS702

MEASURING THE SPECTRAL CONTENT OF A LOGIC IC

In order to analyze the frequency, or spectral content of logic ICs, two measurement techniques have been developed. One method, *The Radiated Measurement Method*, is based on the system-level FCC certification test methodology, FCC Open Site Test (OST) 55. The radiated method utilizes a multilayer PCB with the IC-under-test is mounted on a grounded, adjustable table placed 3 meters from an antenna mast (see *Figure 3*). The IC's input is stimulated by a known periodic waveform and its output drives a typical PCB microstrip. The 75Ω microstrip is properly terminated to prevent reflections from affecting the IC's spectral content results.

The FCC certification test method is an *open field* measurement procedure. Therefore, the spectral content of the device-under-test (in this case, an IC) cannot be detected below the ambient level of radiation. The test-site is permanent and the average ambient noise level remains relatively constant.

The CGS700 and CGS702 were tested for EMI using the above method. A comparison of the EMI results in the form of spectral content is shown in *Figures 4* and *5*.

For more details on EMI, see Application Note AN-831.

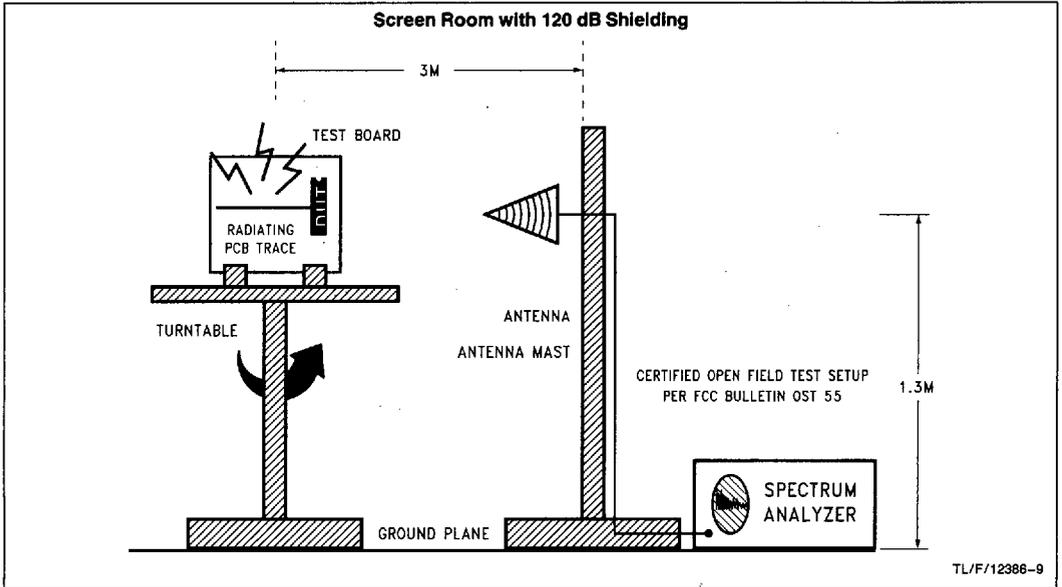
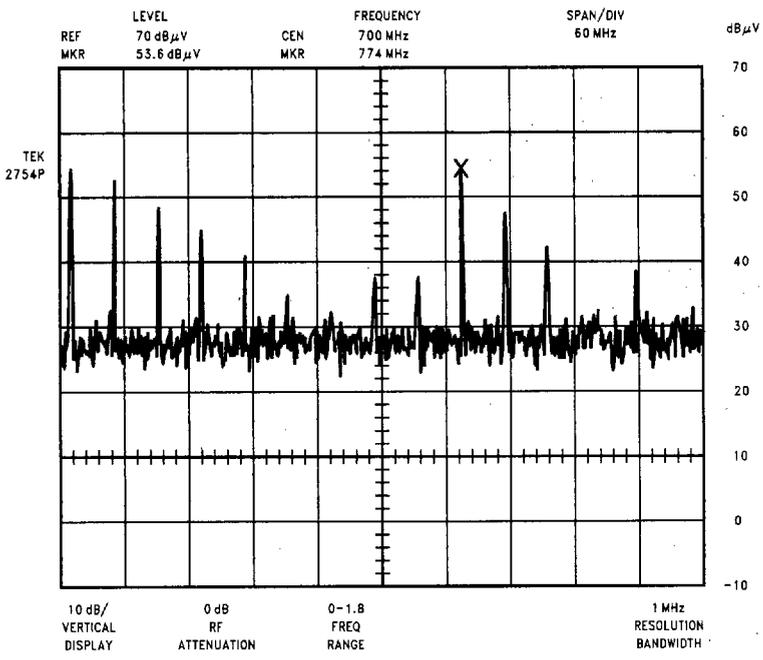


FIGURE 3. Radiated EMI Measurement Method

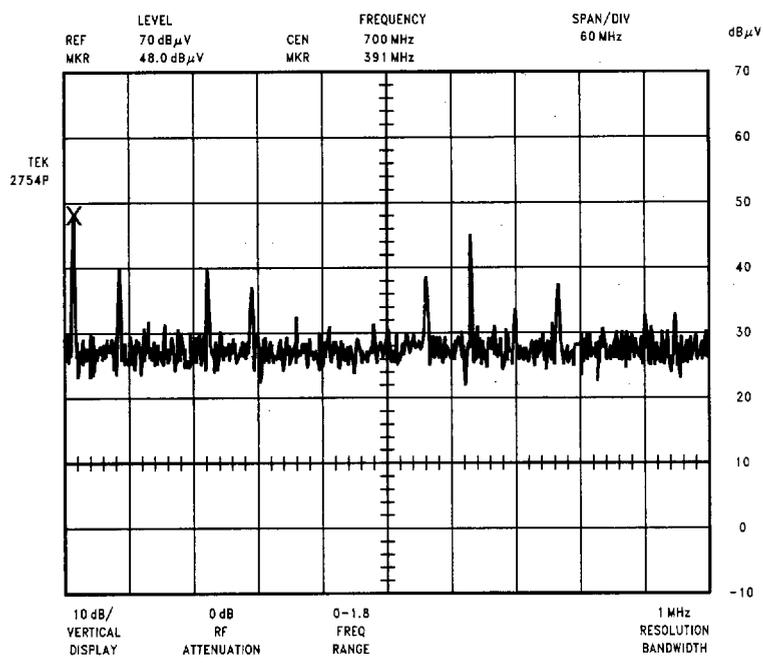
EMI Characteristics and Measurements (Continued)



XTALIN = 40 MHz V_{CC} = 5V T = 25°C ANTENNA = HORIZONTAL

FIGURE 4. CGS700

TL/F/12386-8



XTALIN = 40 MHz V_{CC} = 5V T = 25°C ANTENNA = HORIZONTAL

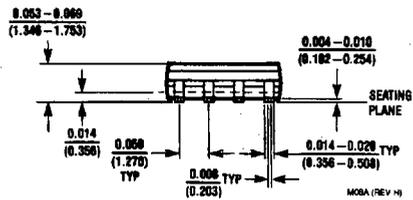
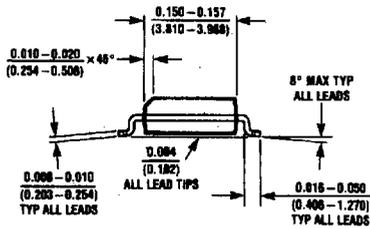
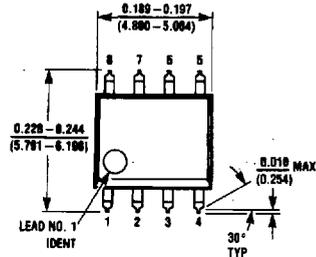
FIGURE 5. CGS702

TL/F/12386-12



8 Lead (0.150" Wide) Molded Small Outline Package, JEDEC NS Package Number M08A

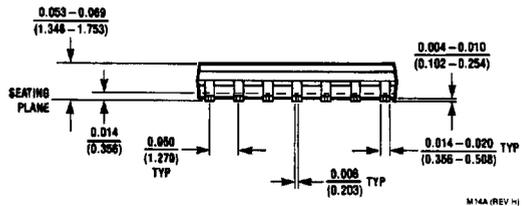
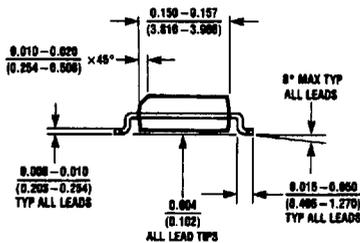
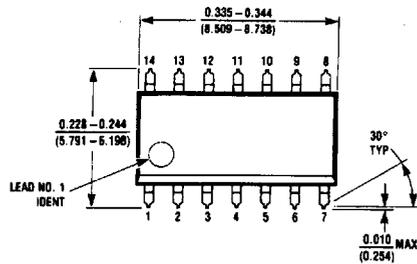
All dimensions are in inches (millimeters)



M08A (REV H)

14 Lead (0.150" Wide) Molded Small Outline Package, JEDEC NS Package Number M14A

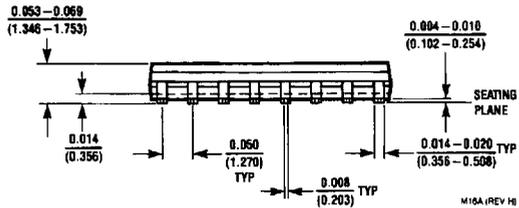
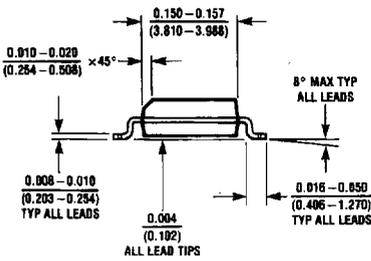
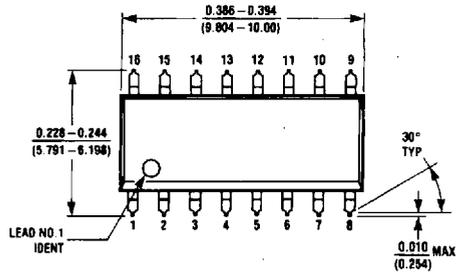
All dimensions are in inches (millimeters)



M14A (REV H)

16 Lead (0.150" Wide) Molded Small Outline Package, JEDEC NS Package Number M16A

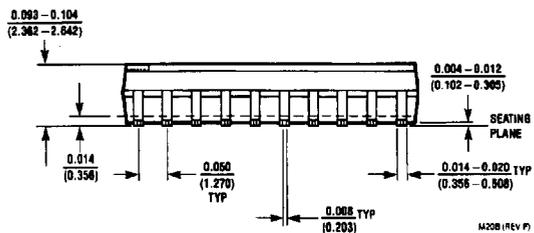
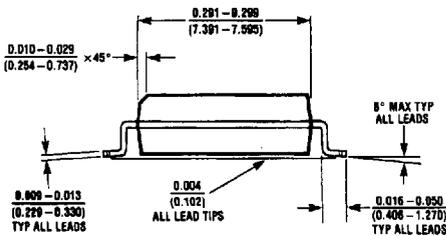
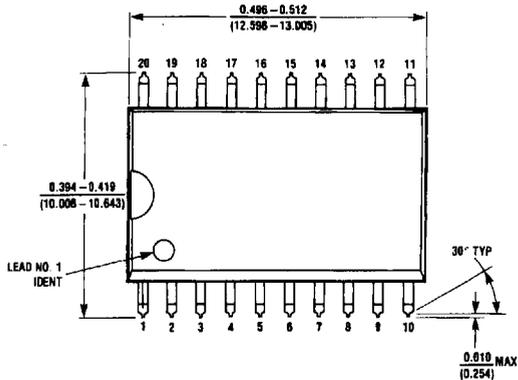
All dimensions are in inches (millimeters)



M16A (REV B)

20 Lead (0.300" Wide) Molded Small Outline Package, JEDEC NS Package Number M20B

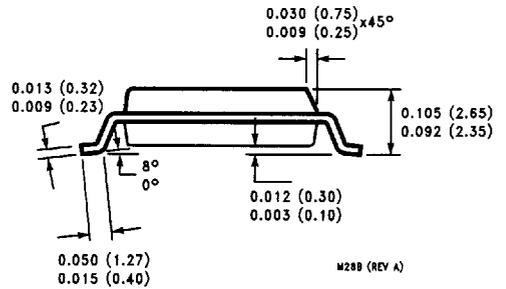
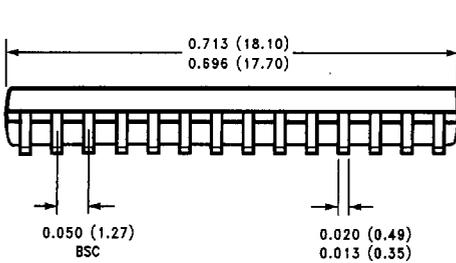
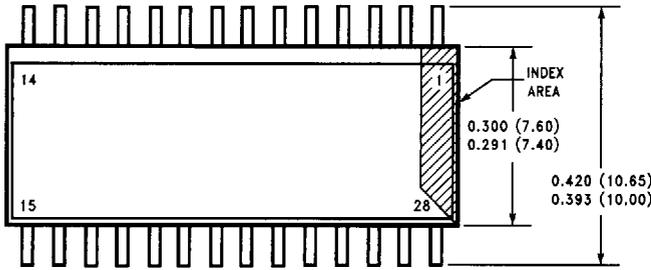
All dimensions are in inches (millimeters)



M20B (REV F)

28 Lead (0.300" Wide) Molded Small Outline Package, JEDEC NS Package Number M28B

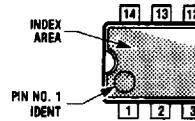
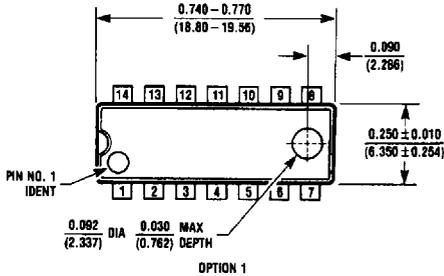
All dimensions are in inches (millimeters)



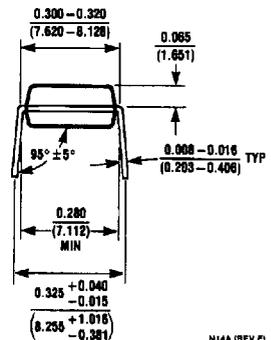
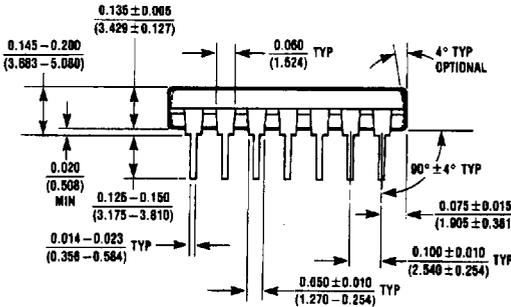
M28B (REV A)

14 Lead (0.300" Wide) Molded Dual-in-Line Package NS Package Number N14A

All dimensions are in inches (millimeters)



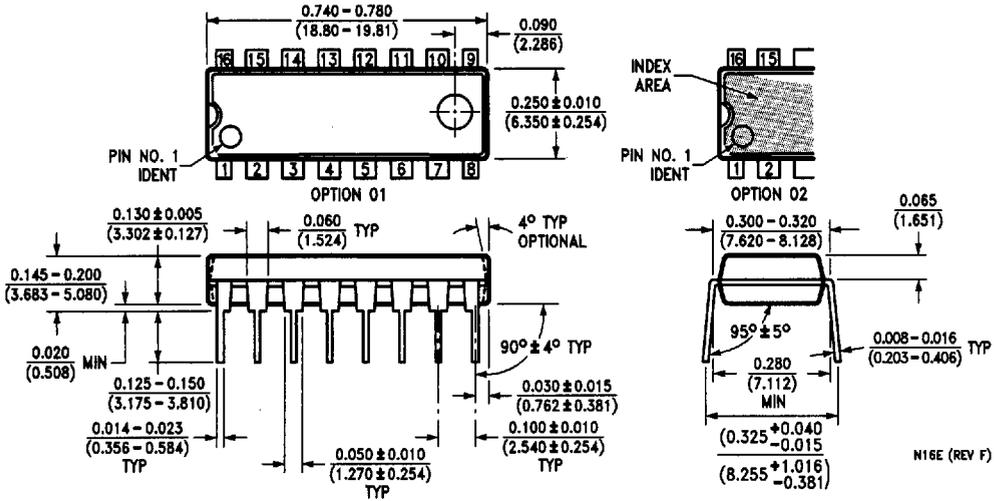
OPTION 02



N14A (REV F)

16 Lead (0.300" Wide) Molded Dual-in-Line Package NS Package Number N16E

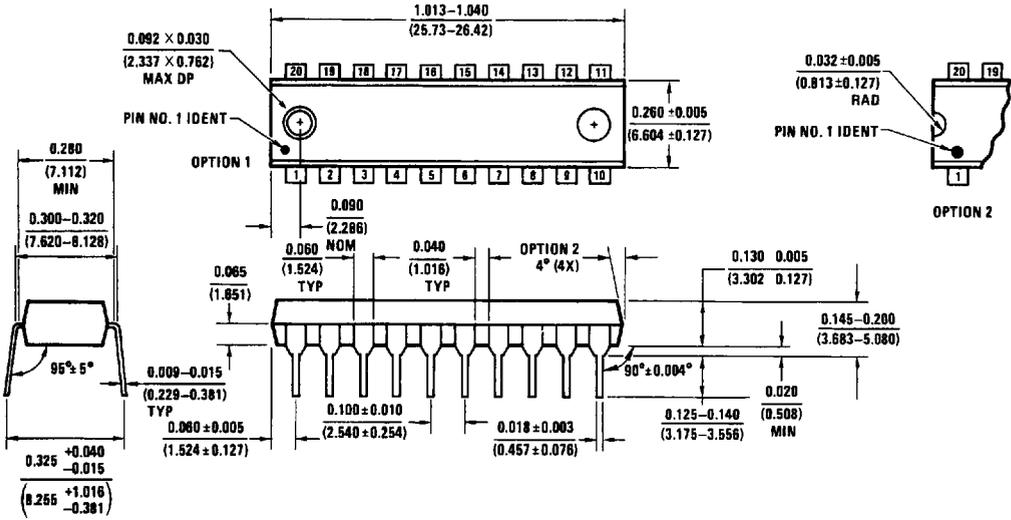
All dimensions are in inches (millimeters)



N16E (REV F)

20 Lead (0.300" Wide) Molded Dual-in-Line Package NS Package Number N20A

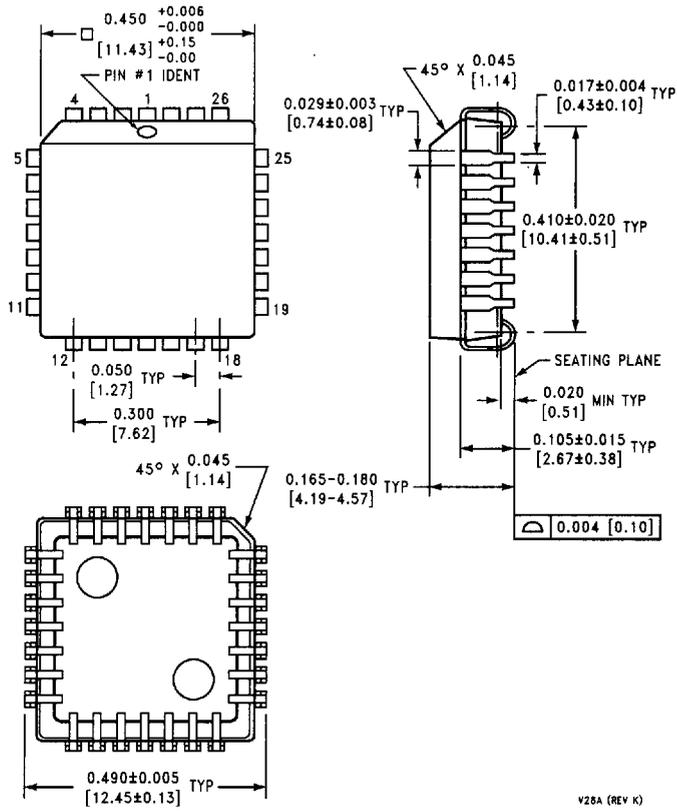
All dimensions are in inches (millimeters)



N20A (REV G)

28 Lead Molded Plastic Leaded Chip Carrier NS Package Number V28A

All dimensions are in inches [millimeters]



V28A (REV K)